NSN 5962-01-172-8638

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-172-8638 **Body Length:** 0.790 inches **Body Width:** 0.285 inches **Body Height:** 0.170 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and programmable and schottky and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.3 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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